NSN 5961-01-165-1673

Photo Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-165-1673 **Inclosure Material:** Metal **Overall Length:** 0.185 inches **Overall Diameter:** 0.340 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.138 inches **Semiconductor Material:** Gallium arsenide Voltage Rating In Volts Per Characteristic: 2.0 reverse voltage, dc **Current Rating Per Characteristic:** 500.00 milliamperes source cutoff current preset **Special Features:** Junction pattern arrangement: pn **Thread Series Designator:** Unc **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a

Demilitarization:

Unit Of Measure:

Yes - demil/mli

Fiig:

A110a0